

SGM8531 SGM8532 SGM8534

500KHz, 18 μ A, Rail-to-Rail I/O CMOS Operational Amplifier

PRODUCT DESCRIPTION

The SGM8531 (single), SGM8532 (dual) and SGM8534 (quad) are rail-to-rail input and output voltage feedback amplifiers offering low cost. They have a wide input common-mode voltage range and output voltage swing, and take the minimum operating supply voltage down to 2.1V and the maximum recommended supply voltage is 5.5 V. All are specified over the extended -40°C to $+125^{\circ}\text{C}$ temperature range.

The SGM8531/8532/8534 provide 500KHz bandwidth at a low current consumption of 18 μ A per amplifier. Very low input bias currents of 0.5 pA, enable the SGM8531/8532/8534 to be used for integrators, photodiode amplifiers, and piezoelectric sensors. Rail-to-Rail inputs and outputs are useful to designers buffering ASIC in single-supply systems.

Applications for these amplifiers include safety monitoring, portable equipment, battery and power supply control, and signal conditioning and interfacing for transducers in very low power systems.

The SGM8531 is available in the tiny SOT23-5 and SO-8 packages. The SGM8532 comes in the miniature SO-8 and MSOP-8 packages. The SGM8534 is offered in TSSOP-14, TSSOP-16, SO-14 and SO-16 packages.

APPLICATIONS

ASIC Input or Output Amplifier
Sensor Interface
Piezo Electric Transducer Amplifier
Medical Instrumentation
Mobile Communication
Audio Output
Portable Systems
Smoke Detectors
Mobile Telephone
Notebook PC
PCMCIA cards
Battery-Powered equipment

FEATURES

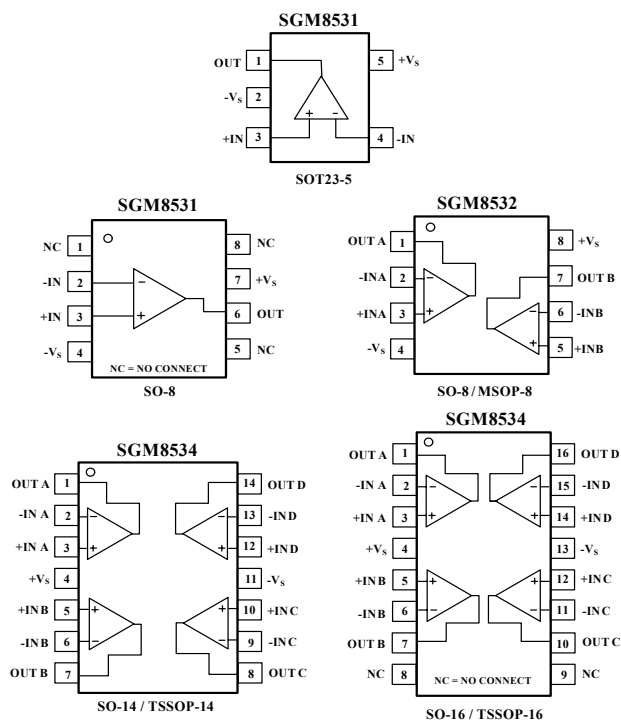
- Low Cost
- Rail-to-Rail Input and Output
0.8mV Typical V_{OS}
- Unity Gain Stable
- Gain Bandwidth Product : 500KHz
- Very low input bias currents : 0.5pA
- Operates on 2.1 V to 5.5 V Supplies
- Input Voltage Range = - 0.1 V to +5.6 V with $V_S = 5.5\text{V}$
- Low Supply Current: 18 μ A/Amplifier
- Small Packaging

SGM8531 Available in SO-8 and SOT23-5

SGM8532 Available in SO-8 and MSOP-8

SGM8534 Available in SO-14, SO-16,
TSSOP-14 and TSSOP-16

PIN CONFIGURATIONS (Top View)



ELECTRICAL CHARACTERISTICS : $V_S = +5V$

(At $R_L = 200k\Omega$ connected to $V_S/2$ and $V_{OUT} = V_S/2$, unless otherwise noted)

PARAMETER	Symbol	CONDITION	SGM8531/8532/8534							
			TYP	MIN/MAX OVER TEMPERATURE					UNITS	MIN/MAX
				+25℃	+25℃	0℃ to 70℃	- 40℃ to +85℃	- 40℃ to +125℃		
INPUT CHARACTERISTICS										
Input Offset Voltage	V _{OS}	V _S = 5.5V	±0.8	±3.5	±3.7	±4.1	±5.4	mV	MAX	
Input Bias Current	I _B		0.5					pA	TYP	
Input Offset Current	I _{OS}		0.5					pA	TYP	
Common-Mode Voltage Range	V _{CM}		-0.1 to +5.6					V	TYP	
Common-Mode Rejection Ratio	CMRR	V _S = 5.5V, V _{CM} = -0.1V to 4 V	92	72	72	71	71	dB	MIN	
		V _S = 5.5V, V _{CM} = -0.1V to 5.6 V	83	63	62	61	61	dB	MIN	
Open-Loop Voltage Gain	A _{OL}	R _L = 5KΩ ,Vo = 0.1V to 4.9V	100	84	84	84	82	dB	MIN	
		R _L =100KΩ ,Vo = 0.035V to 4.965V	104	90	90	90	89	dB	MIN	
Input Offset Voltage Drift	ΔV _{OS} /ΔT		1.7					μV/℃	TYP	
OUTPUT CHARACTERISTICS										
Output Voltage Swing from Rail	I _{OUT}	R _L = 100KΩ	0.008					V	MAX	
Output Current			22	20	19.1	18.8	18	mA	MIN	
POWER SUPPLY										
Operating Voltage Range	PSRR	V _s = +2.5 V to + 5.5 V V _{CM} = (-V _S) + 0.5		2.1 5.5	2.5 5.5	2.5 5.5	2.5 5.5	V V	MIN MAX	
Power Supply Rejection Ratio			90	76	73	71	71	dB	MIN	
Quiescent Current / Amplifier	I _Q	I _{OUT} = 0	18	24	26.6	27.4	29.7	μA	MAX	
DYNAMIC PERFORMANCE										
Gain-Bandwidth Product	GBP	C _L = 100pF	500					KHz	TYP	
Slew Rate	SR	G = +1 , 2V Output Step	0.2					V/μs	TYP	
Settling Time to 0.1%	t _s	G = +1, 2 V Output Step	18					μs	TYP	
Overload Recovery Time		V _{IN} ·Gain = Vs	16					μs	TYP	
NOISE PERFORMANCE										
Voltage Noise Density	e _n	f = 1kHz	37					nV/√Hz	TYP	
		f = 10kHz	28					nV/√Hz	TYP	

Specifications subject to change without notice.

PACKAGE/ORDERING INFORMATION

MODEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
SGM8531	SGM8531XN5/TR	SOT23-5	Tape and Reel, 3000	8531
	SGM8531XS/TR	SO-8	Tape and Reel, 2500	SGM8531XS
SGM8532	SGM8532XS/TR	SO-8	Tape and Reel, 2500	SGM8532XS
	SGM8532XMS/TR	MSOP-8	Tape and Reel, 3000	SGM8532XMS
SGM8534	SGM8534XS/TR	SO-16	Tape and Reel, 2500	SGM8534XS
	SGM8534XS14	SO-14	Tube	SGM8534XS14
	SGM8534XTS/TR	TSSOP-16	Tape and Reel, 3000	SGM8534XTS
	SGM8534XTS14	TSSOP-14	Tube	SGM8534XTS14

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V₊ to V₋ 7.5 V
Common-Mode Input Voltage
..... (–V_S) – 0.5 V to (+V_S) +0.5V
Storage Temperature Range..... –65°C to +150°C
Junction Temperature160°C
Operating Temperature Range –55°C to +150°C
Package Thermal Resistance @ T_A = 25°C
SOT23-5, θ_{JA}..... 190°C/W
SO-8, θ_{JA}.....125°C/W
MSOP-8, θ_{JA}..... 216°C/W
SO-16, θ_{JA}..... 82°C/W
TSSOP-16, θ_{JA}..... 105°C/W
Lead Temperature Range (Soldering 10 sec)
.....260°C
ESD Susceptibility
HBM.....4000V
MM.....400V

NOTES

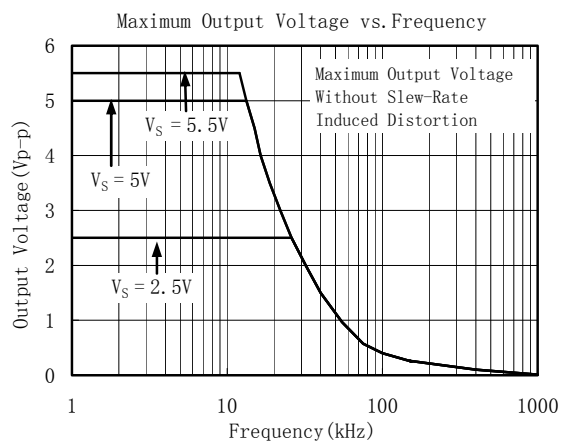
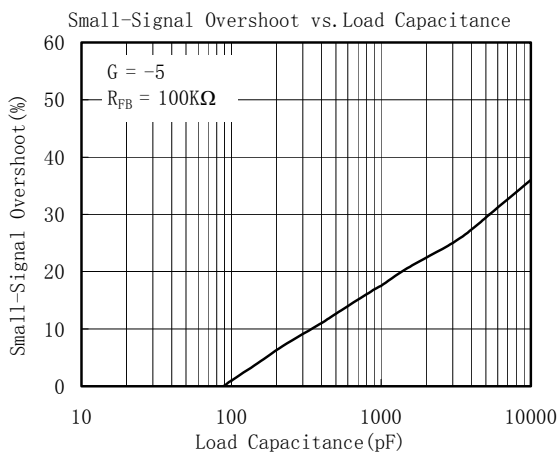
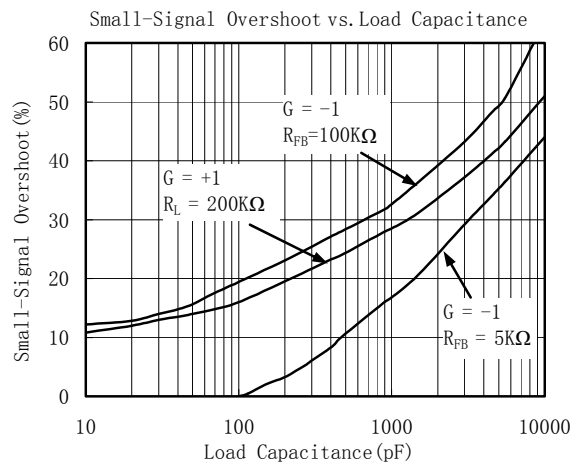
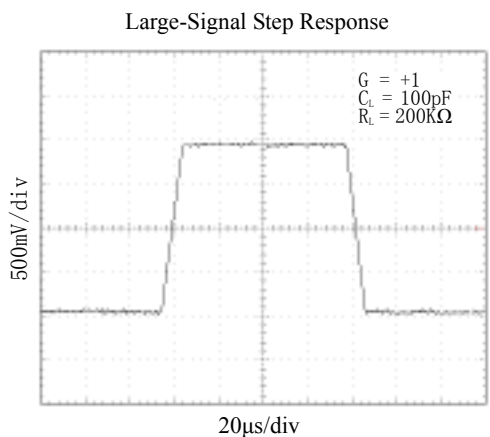
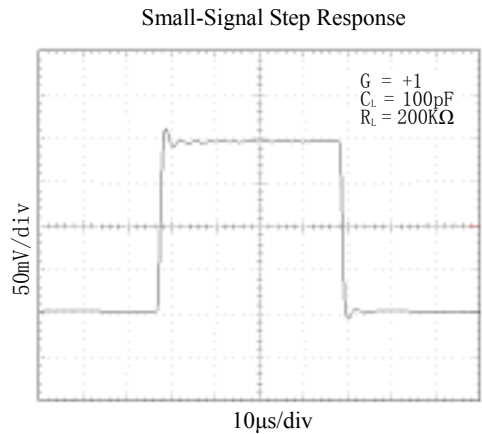
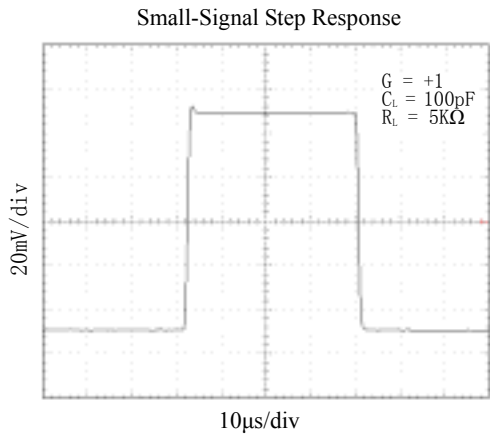
1. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

This integrated circuit can be damaged by ESD. Shengbang Micro-electronics recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.
ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

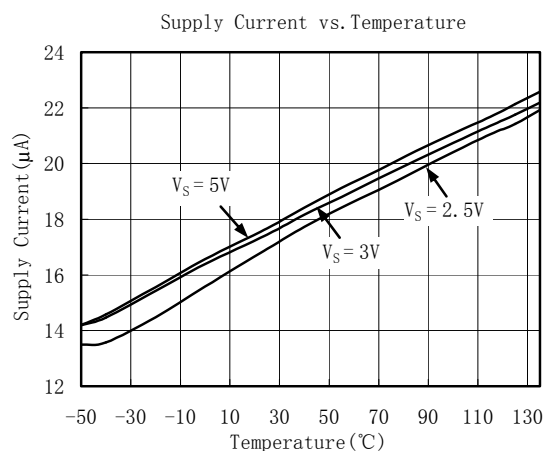
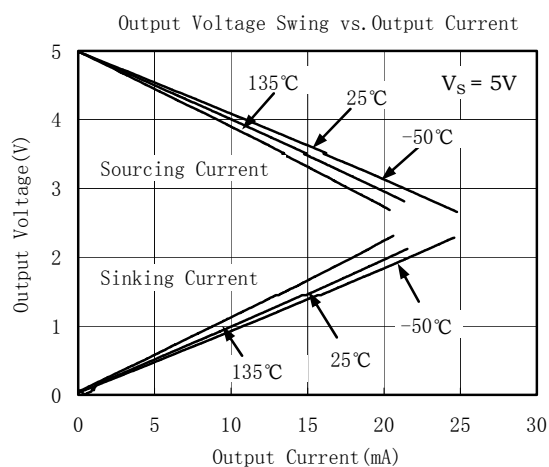
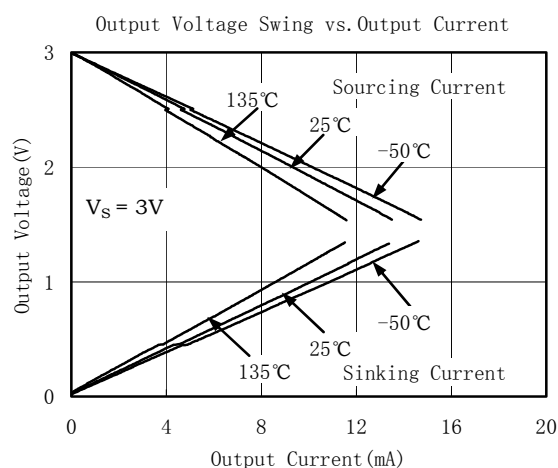
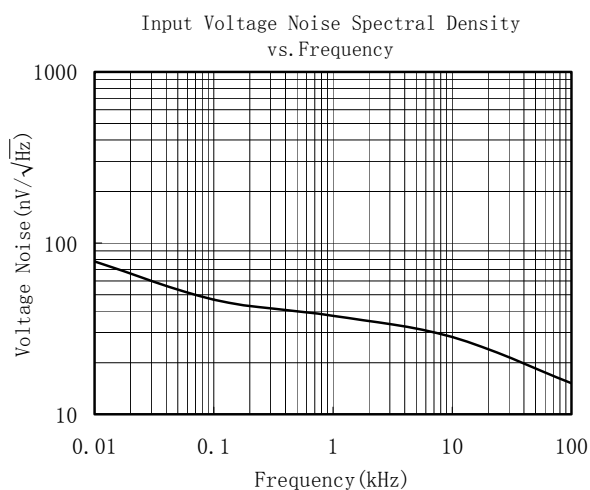
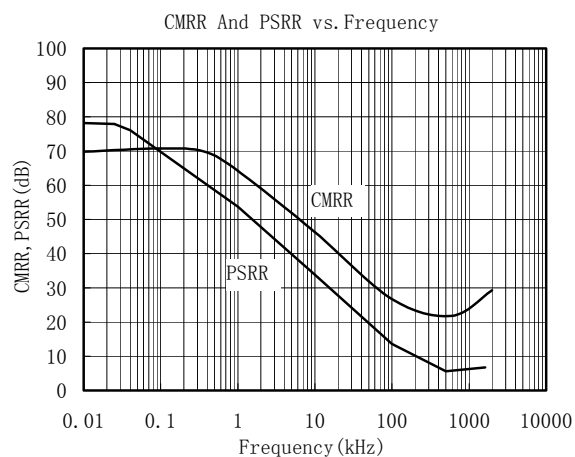
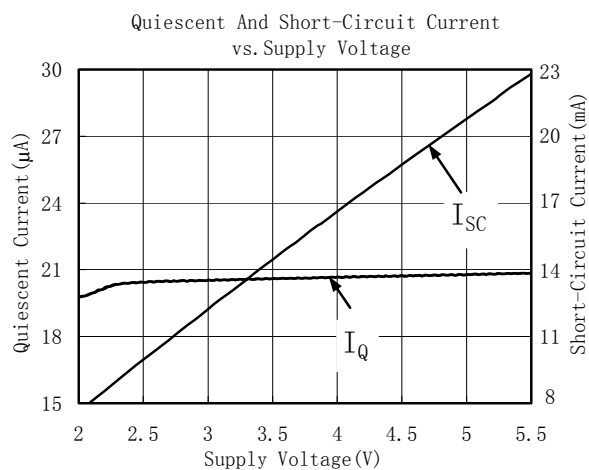
TYPICAL PERFORMANCE CHARACTERISTICS

At $T_A = +25^{\circ}\text{C}$, $V_S = +5\text{V}$, and $R_L = 200\text{k}\Omega$ connected to $V_S/2$, unless otherwise noted.



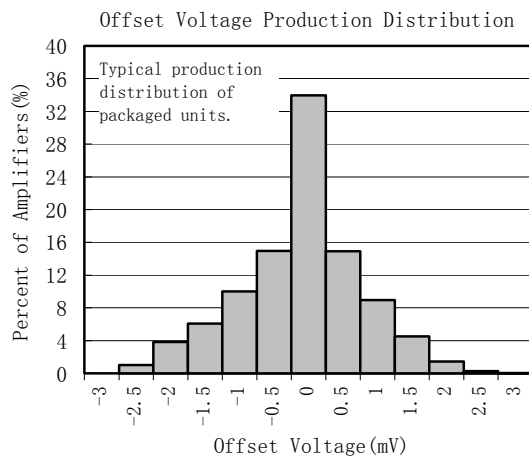
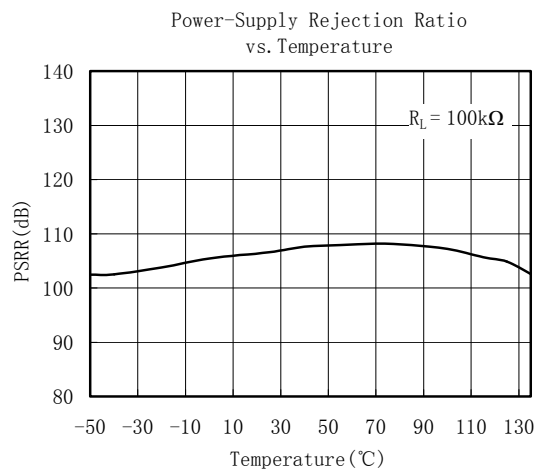
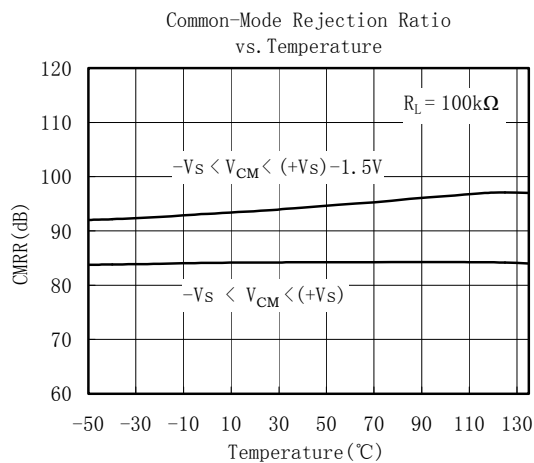
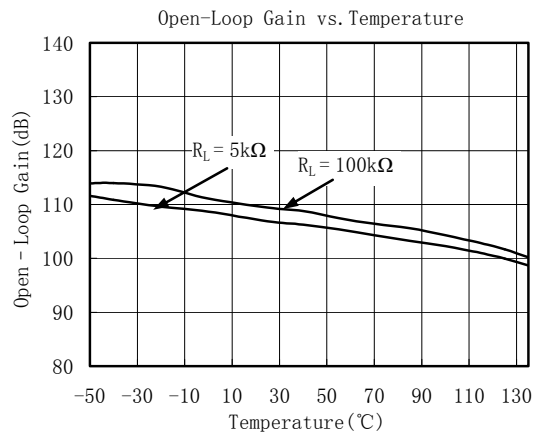
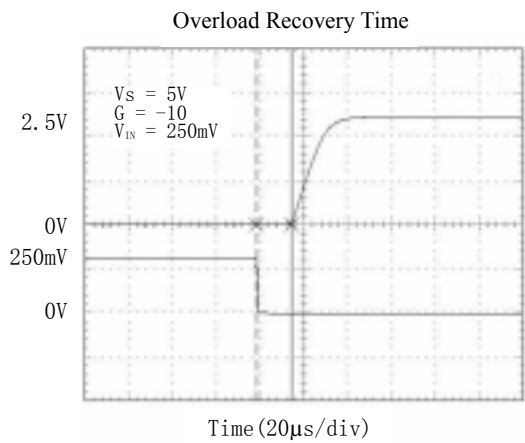
TYPICAL PERFORMANCE CHARACTERISTICS

At $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, and $R_L = 200\text{k}\Omega$ connected to $V_S/2$, unless otherwise noted.



TYPICAL PERFORMANCE CHARACTERISTICS

At $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, and $R_L = 200\text{k}\Omega$ connected to $V_S/2$, unless otherwise noted.



APPLICATION NOTES

Driving Capacitive Loads

The SGM853X can directly drive 250pF in unity-gain without oscillation. The unity-gain follower (buffer) is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers and this results in ringing or even oscillation. Applications that require greater capacitive drive capability should use an isolation resistor between the output and the capacitive load like the circuit in Figure 1. The isolation resistor R_{ISO} and the load capacitor C_L form a zero to increase stability. The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. Note that this method results in a loss of gain accuracy because R_{ISO} forms a voltage divider with the R_{LOAD} .

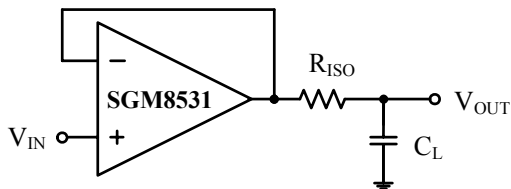


Figure 1. Indirectly Driving Heavy Capacitive Load

An improvement circuit is shown in Figure 2. It provides DC accuracy as well as AC stability. R_F provides the DC accuracy by connecting the inverting signal with the output, C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.

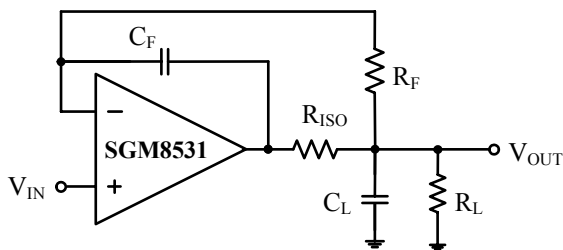


Figure 2. Indirectly Driving Heavy Capacitive Load with DC Accuracy

For no-buffer configuration, there are two others ways to increase the phase margin: (a) by increasing the amplifier's gain or (b) by placing a capacitor in parallel with the feedback resistor to counteract the parasitic capacitance associated with inverting node.

Power-Supply Bypassing and Layout

The SGM853X family operates from either a single +2.5V to +5.5V supply or dual $\pm 1.25V$ to $\pm 2.75V$ supplies. For single-supply operation, bypass the power supply V_{DD} with a 0.1 μF ceramic capacitor which should be placed close to the V_{DD} pin. For dual-supply operation, both the V_{DD} and the V_{SS} supplies should be bypassed to ground with separate 0.1 μF ceramic capacitors. 2.2 μF tantalum capacitor can be added for better performance.

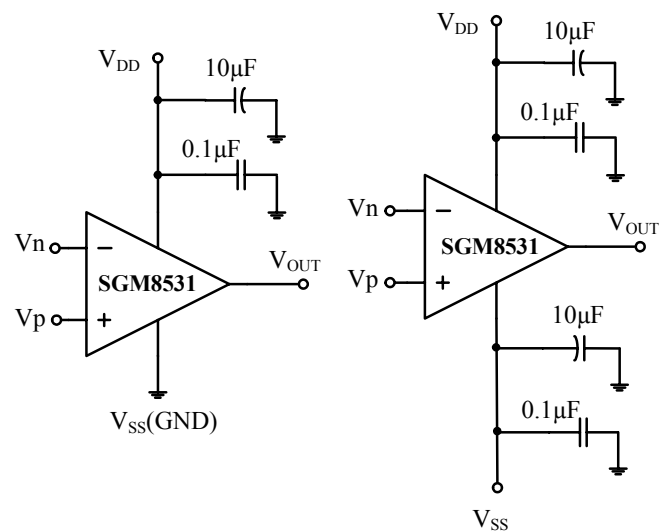


Figure 3. Amplifier with Bypass Capacitors

Typical Application Circuits

Differential Amplifier

The circuit shown in Figure 4 performs the difference function. If the resistors ratios are equal ($R_4 / R_3 = R_2 / R_1$), then $V_{OUT} = (V_p - V_n) \times R_2 / R_1 + V_{ref}$.

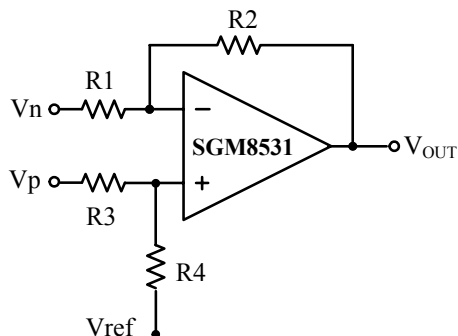


Figure 4. Differential Amplifier

Instrumentation Amplifier

The circuit in Figure 5 performs the same function as that in Figure 4 but with the high input impedance.

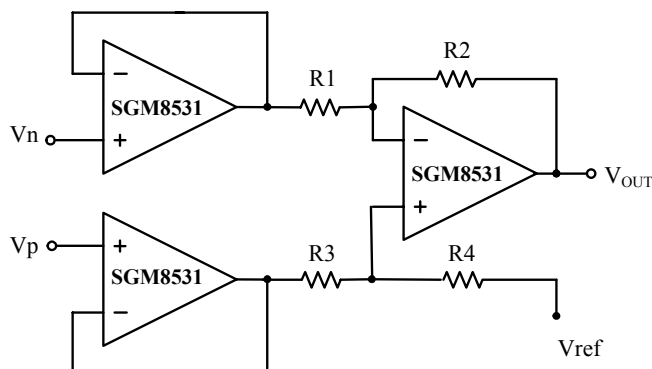


Figure 5. Instrumentation Amplifier

Low Pass Active Filter

The low pass filter shown in Figure 6 has a DC gain of ($-R_2 / R_1$) and the -3dB corner frequency is $1/2\pi R_2 C$. Make sure the filter is within the bandwidth of the amplifier. The Large values of feedback resistors can couple with parasitic capacitance and cause undesired effects such as ringing or oscillation in high-speed amplifiers. Keep resistors value as low as possible and consistent with output loading consideration.

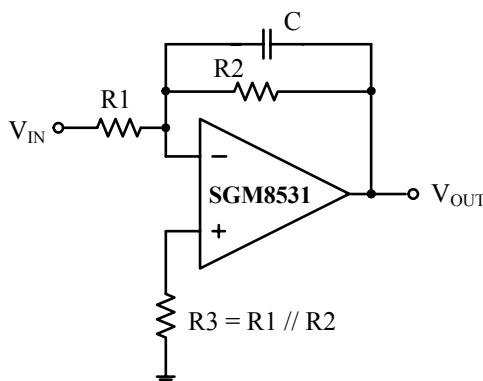
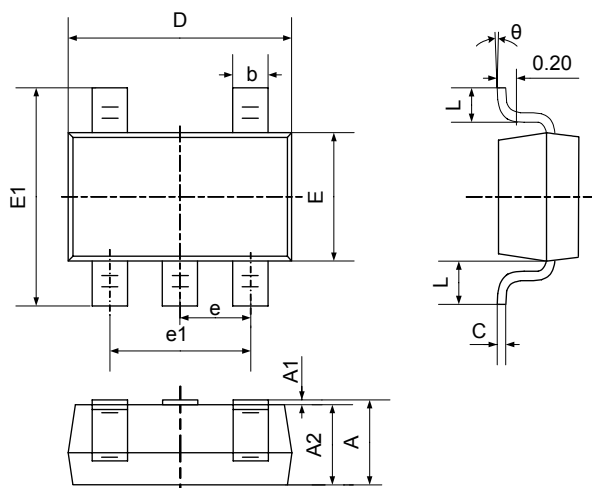


Figure 6. Low Pass Active Filter

PACKAGE OUTLINE DIMENSIONS

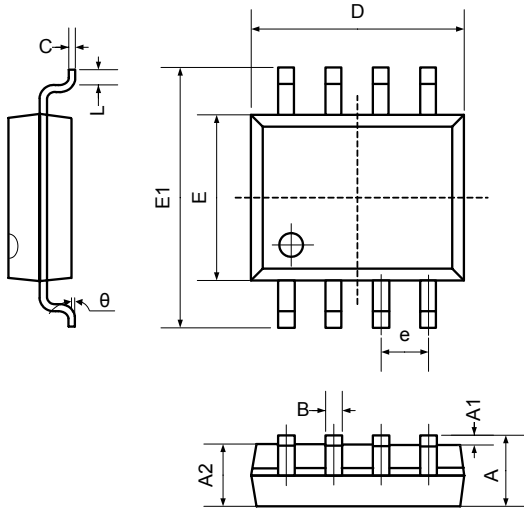
SOT23-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.028REF	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

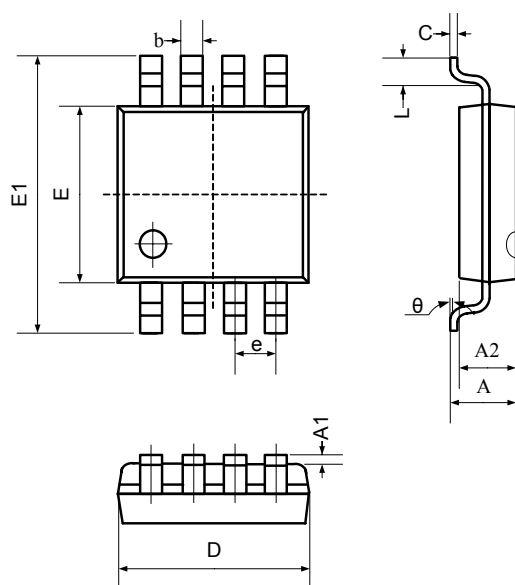
SO-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
B	0.330	0.510	0.013	0.020
C	0.190	0.250	0.007	0.010
D	4.780	5.000	0.188	0.197
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.248
e	1.270TYP		0.050TYP	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

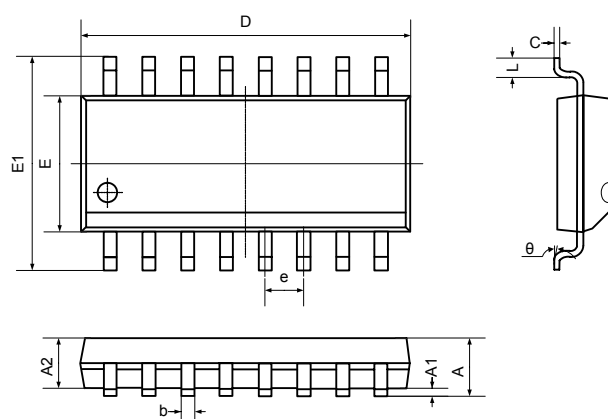
MSOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.800	1.200	0.031	0.047
A1	0.000	0.200	0.000	0.008
A2	0.760	0.970	0.030	0.038
b	0.30 TYP		0.012 TYP	
c	0.15 TYP		0.006 TYP	
D	2.900	3.100	0.114	0.122
e	0.65 TYP		0.026 TYP	
E	2.900	3.100	0.114	0.122
E1	4.700	5.100	0.185	0.201
L	0.410	0.650	0.016	0.026
θ	0°	6°	0°	6°

PACKAGE OUTLINE DIMENSIONS

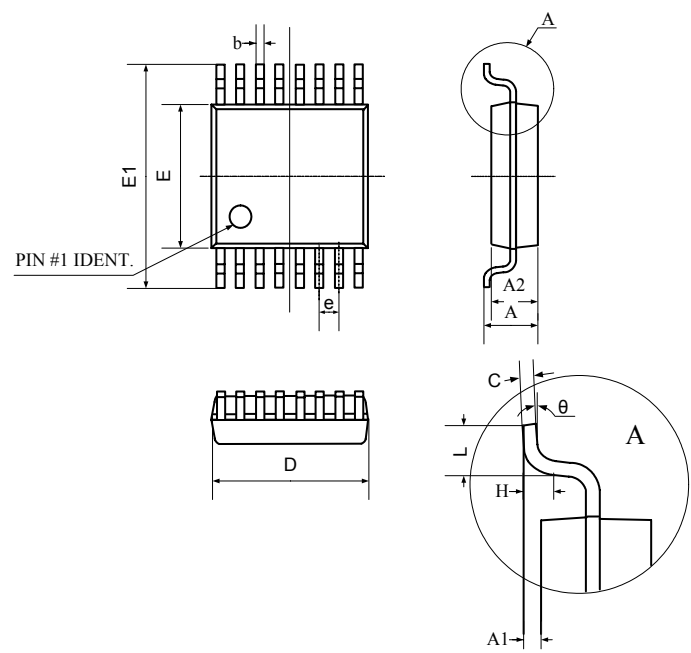
SO-16



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	9.800	10.20	0.386	0.402
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

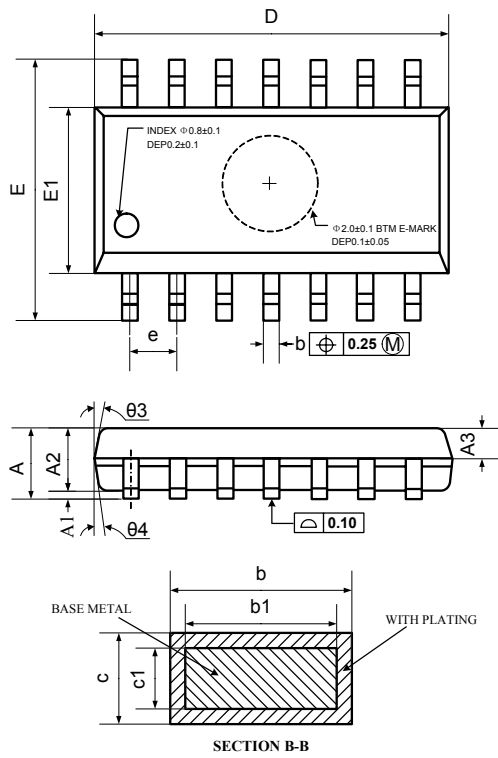
TSSOP-16



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
D	4.900	5.100	0.193	0.201
E	4.300	4.500	0.169	0.177
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
E1	6.250	6.550	0.246	0.258
A		1.100		0.043
A2	0.800	1.000	0.031	0.039
A1	0.020	0.150	0.001	0.006
e	0.65 (BSC)		0.026 (BSC)	
L	0.500	0.700	0.020	0.028
H	0.25(TYP)		0.01(TYP)	
θ	1°	7°	1°	7°

PACKAGE OUTLINE DIMENSIONS

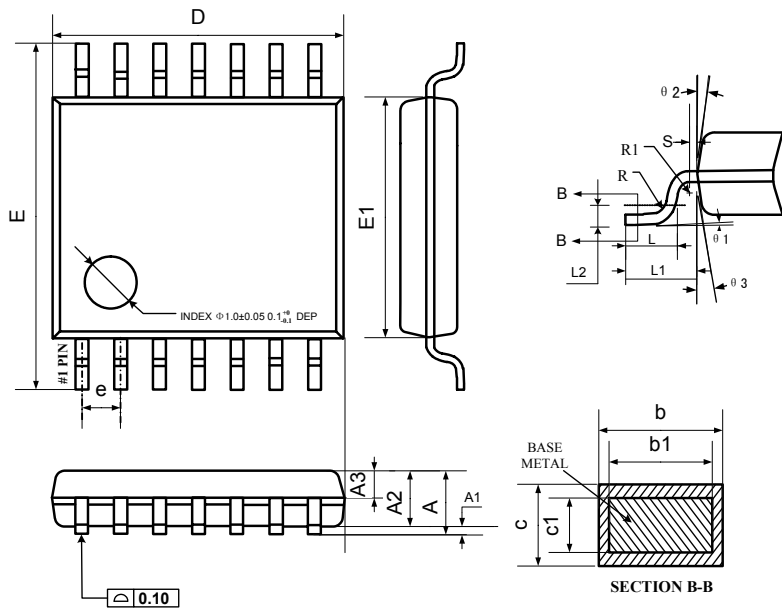
SO-14



Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	1.35	1.60	1.75
A1	0.10	0.15	0.25
A2	1.25	1.45	1.65
A3	0.55	0.65	0.75
b	0.36		0.49
b1	0.35	0.40	0.45
c	0.16		0.25
c1	0.15	0.20	0.25
D	8.53	8.63	8.73
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.27 BSC		
L	0.45	0.60	0.80
L1	1.04 REF		
L2	0.25 BSC		
R	0.07		
R1	0.07		
h	0.30	0.40	0.50
θ	0°		8°
$\theta 1$	6°	8°	10°
$\theta 2$	6°	8°	10°
$\theta 3$	5°	7°	9°
$\theta 4$	5°	7°	9°

PACKAGE OUTLINE DIMENSIONS

TSSOP-14



Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	—	—	1.20
A1	0.05	—	0.15
A2	0.90	1.00	1.05
A3	0.34	0.44	0.54
b	0.20	—	0.28
b1	0.20	0.22	0.24
c	0.10	—	0.19
c1	0.10	0.13	0.15
D	4.86	4.96	5.06
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
L2	0.25 BSC		
R	0.09	—	—
R1	0.09	—	—
S	0.20	—	—
$\theta 1$	0°	—	8°
$\theta 2$	10°	12°	14°
$\theta 3$	10°	12°	14°

REVISION HISTORY

Location	Page
11/06— Data Sheet changed from REV.A to REV.B	
Changes to ABSOLUTE MAXIMUM RATINGS	3
05/07— Data Sheet changed from REV.B to REV.C	
Adds SO-14 and TSSOP-14 Package	1,3,14,15

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